



Operational Amplifier

High Speed Ground Sense Excellent EMI Characteristics CMOS Operational Amplifier

BD77501G BD77502FVM BD77504FV

General Description

BD77501G, BD77502FVM and BD77504FV are single/dual/quad Ground Sense CMOS operational amplifier. An operating voltage range is wide with 7 V to 15 V. This operational amplifier is the most suitable for various applications especially sensor amplifier and so on because it has features of high slew rate and low input bias current.

Also, BD77501G, BD77502FVM and BD77504FV have the advantage of EMI tolerance. It makes easier replacing with conventional products or simpler designing EMI.

Furthermore, this circuit type does not oscillate even with a capacitance of several nF. Set design is possible without worrying about oscillation due to output capacitance.

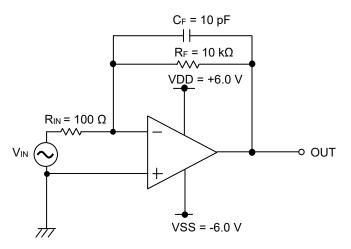
Features

- EMARMOUR[™] Series
- Nano Cap[™] integrated OPAMP
- Operating with a Single Power Supply
- Input and output are operable GND sense
- High Slew Rate
- Wide Operating Supply Voltage Range
- High Open Loop Voltage Gain

Applications

- Sensor Amplifier
- Buffer Application Amplifier
- Current Monitoring Amplifier
- Consumer Electronics

Typical Application Circuit



Key Specifications

- Input Offset Voltage: 4 mV (Typ)
- Common-mode Input Voltage Range:
- V_{SS} to V_{DD}-2.0 V

 ■ Slew Rate:
 10 V/µs (Typ)

Operating Supply Voltage Range	,
Single Supply:	7 V to 15 V
Dual Supply:	±3.5 V to ±7.5 V
Operating Temperature Range:	-40 °C to +85 °C



W (Typ) x D (Typ) x H (Max) 2.9 mm x 2.8 mm x 1.25 mm 2.9 mm x 4.0 mm x 0.9 mm 5.0 mm x 6.4 mm x 1.35 mm





SSOP5

MSOP8



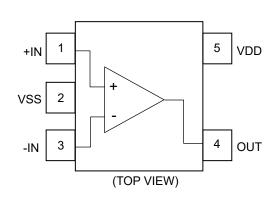
SSOP-B14

 $V_{OUT} = -\frac{R_F}{R_{IN}}V_{IN}$

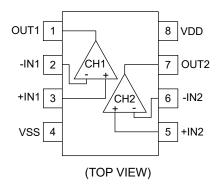
EMARMOUR[™] and Nano Cap[™] are a trademark or a registered trademark of ROHM Co., Ltd.

OProduct structure : Silicon integrated circuit OThis product has no designed protection against radioactive rays.

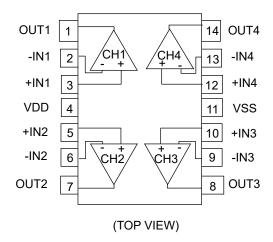
Pin Configuration BD77501G



BD77502FVM



BD77504FV



Pin Description

BD77501G

0010		
Pin No.	Pin Name	Function
1	+IN	Non-inverting input
2	VSS	Negative power supply / Ground
3	-IN	Inverting input
4	OUT	Output
5	VDD	Positive power supply

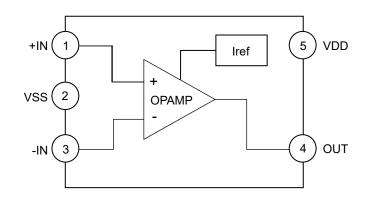
BD77502FVM

Pin No.	Pin Name	Function				
1	OUT1	Output (1ch)				
2	-IN1	Inverting input (1ch)				
3	+IN1	Non-inverting input (1ch)				
4	VSS	Negative power supply / Ground				
5	+IN2	Non-inverting input (2ch)				
6	-IN2	Inverting input (2ch)				
7	OUT2	Output (2ch)				
8	VDD	Positive power supply				

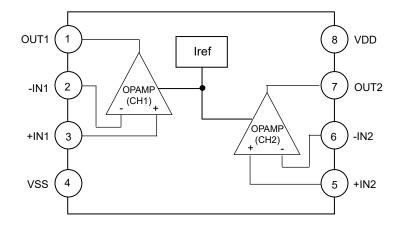
BD77504FV

Pin No.	Pin Name	Function				
1	OUT1	Output (1ch)				
2	-IN1	Inverting input (1ch)				
3	+IN1	Non-inverting input (1ch)				
4	VDD	Positive power supply				
5	+IN2	Non-inverting input (2ch)				
6	-IN2	Inverting input (2ch)				
7	OUT2	Output (2ch)				
8	OUT3	Output (3ch)				
9	-IN3	Inverting input (3ch)				
10	+IN3	Non-inverting input (3ch)				
11	VSS	Negative power supply / Ground				
12	+IN4	Non-inverting input (4ch)				
13	-IN4	Inverting input (4ch)				
14	OUT4	Output (4ch)				

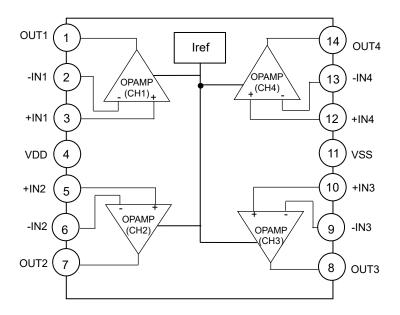
Block Diagram BD77501G



BD77502FVM



BD77504FV



Description of Blocks

OPAMP: 1.

This block is a full-swing output operational amplifier with class-AB output circuit and ground-sense differential input stage.

2. Iref:

This block supplies reference current which is needed to operate OPAMP block.

Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Rating	Unit
Supply Voltage	V _{DD} -V _{SS}	15.5	V
Differential Input Voltage ^(Note 1)	Vid	V _{DD} -V _{SS}	V
Common-mode Input Voltage Range	VICMR	(Vss - 0.3) to (V _{DD} + 0.3)	V
Input Current	I.	±10	mA
Maximum Junction Temperature	Tjmax	150	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operate over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

(Note 1) The differential input voltage indicates the voltage difference between inverting input and non-inverting input.

The input pin voltage is set to V_{SS} or more.

Thermal Resistance^(Note 2)

Demonster	Querra ha a h	Thermal Res			
Parameter	Symbol –	1s ^(Note 4)	2s2p ^(Note 5)	Unit	
SSOP5	I I		1	- #	
Junction to Ambient	θյΑ	376.5	185.4	°C/W	
Junction to Top Characterization Parameter ^(Note 3)	Ψ _{JT}	40	30	°C/W	
MSOP8					
Junction to Ambient	θ _{JA}	284.1	135.4	°C/W	
Junction to Top Characterization Parameter ^(Note 3)	Ψյτ	21	11	°C/W	
SSOP-B14	<u>i</u>				
Junction to Ambient	θյΑ	159.6	92.8	°C/W	
Junction to Top Characterization Parameter ^(Note 3)	Ψյτ	13	9	°C/W	

(Note 2) Based on JESD51-2A (Still-Air).

(Note 3) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

(Note 4) Using a PCB board based on JESD51-3.

(<u>N</u>	ote 5) Using a PCB board based or	n JESD51-7.			
	Layer Number of Measurement Board	Material	Board Size		
	Single	FR-4	114.3 mm x 76.2 mm x	c 1.57 mmt	
	Тор				
	Copper Pattern	Thickness			
	Footprints and Traces	70 µm			
	Layer Number of Measurement Board	Material	Board Size		
	4 Layers	FR-4	114.3 mm x 76.2 mm	x 1.6 mmt	
Γ	Тор		2 Internal Laye	ers	Bottom
	Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern
	Footprints and Traces	70 µm	74.2 mm x 74.2 mm	35 µm	74.2 mm x 74.2 mm

Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit
Operating Supply Voltage	V _{DD}	7.0 ±3.5	12.0 ±6.0	15.0 ±7.5	V
Operating Temperature	Topr	-40	+25	+85	°C
Output Load Capacitance ^(Note 6)	CL	-	0.01	-	nF

(Note 6) This parameter obtained V_{DD} = 12 V. Not 100 % tested.

Thickness 70 µm

Function Explanation

1. EMARMOUR™

EMARMOUR[™] is the brand name given to ROHM products developed by leveraging proprietary technologies covering layout, process, and circuit design to achieve ultra-high noise immunity that limits output voltage fluctuation to ±300 mV or less across the entire noise frequency band during noise evaluation testing under the international ISO11452-2 standard. This unprecedented noise immunity reduces design load while improving reliability by solving issues related to noise in the development of vehicle electrical systems.

2. Nano Cap[™]

Nano Cap^{TM} is a combination of technologies which allow stable operation even if output capacitance is connected with the range of nF unit. This circuit type does not oscillate even with a capacitance of several nF. Set design is possible without worrying about oscillation due to output capacitance.

Electrical Characteristics (Unless otherwise specified V_{DD} = 12 V, V_{SS} = 0 V, Ta = 25 °C)

oBD77501G

Deremeter	Symbol	Temperature	Limit				
Parameter		Range	Min	Тур	Max	Unit	Conditions
Input Offset Voltage	Vio	25 °C	-	4	27	mV	Absolute value
Input Offset Current	l _{io}	25 °C	-	0.001	-	nA	Absolute value
Input Bias Current	lΒ	25 °C	-	0.001	-	nA	Absolute value
		25 °C	-	1.3	3.0		
Supply Current	lod	-40 °C to +85 °C	-	-	4.5	mA	R _L = ∞, G = 0 dB
		25 °C	-	0.06	0.25		R∟= 10 kΩ,
Output Voltage High	Vон	-40 °C to +85 °C	-	-	0.3	V	V _{OH} = V _{DD} -V _{OUT}
		25 °C	-	0.07	0.25	V	D 4010
Output Voltage Low	Vol	-40 °C to +85 °C	-	-	0.3	V	R∟= 10 kΩ
		25 °C	60	75	-	- dB	-
Large Signal Voltage Gain	Av	-40 °C to +85 °C	55	-	-		
Common-mode Input Voltage Range ^(Note 1)	VICMR	25 °C	0	-	V _{DD} -2.0	V	-
Common-mode Rejection		25 °C	50	70	-	dB	
Ratio	CMRR	-40 °C to +85 °C	45	-	-	aв	-
Power Supply Rejection	DODD	25 °C	50	70	-		
Ratio	PSRR	-40 °C to +85 °C	40	-	-	dB	-
		25 °C	2	7.5	-		V _{OUT} = V _{DD} -0.4 V
Output Source Current ^(Note 2)	Іон	-40 °C to +85 °C	1	-	-	mA	Absolute value
Quite at Qiela Quiere (Note 2)		25 °C	3.5	6.0	-		V _{OUT} = V _{SS} +0.4 V
Output Sink Current ^(Note 2)	IOL	-40 °C to +85 °C	1	-	-	mA	Absolute value
Slew Rate	SR	25 °C	-	10	-	V/µs	C _L = 10 pF
Gain Bandwidth Product	GBW	25 °C	-	8	-	MHz	G = 40 dB
Total Harmonic Distortion + Noise	THD+N	25 °C	-	0.05	-	%	V _{OUT} = 4 V _{P-P} , LPF = 80 kHz, f = 1 kHz

(Note 1) Not 100% tested.

(Note 2) Consider the power dissipation of the IC under high temperature environment when selecting the output current value. When the output pin is shortcircuited continuously, the output current may decrease due to the temperature rise by the heat generation of inside the IC.

Electrical Characteristics (Unless otherwise specified V_{DD} = 12 V, V_{SS} = 0 V, Ta = 25 °C) - continued $_{\odot}\text{BD77502FVM}$

Parameter	Symbol	Temperature		Limit		Unit	Conditions
Falameter		Range	Min	Тур	Max	Unit	Conditions
Input Offset Voltage	Vio	25 °C	-	4	27	mV	Absolute value
Input Offset Current	l _{io}	25 °C	-	0.001	-	nA	Absolute value
Input Bias Current	lв	25 °C	-	0.001	-	nA	Absolute value
Supply Current	1	25 °C	-	2.6	6.0	mΛ	$\mathbf{P} = \mathbf{e} \cdot \mathbf{C} = 0 \mathbf{d} \mathbf{P}$
Supply Current	IDD	-40 °C to +85 °C	-	-	9.0	mA	R _L = ∞, G = 0 dB
Output Voltage Lligh	Maria	25 °C	-	0.06	0.25	V	R∟= 10 kΩ,
Output Voltage High	Vон	-40 °C to +85 °C	-	-	0.3	V	VOH = VDD-VOUT
Output Voltage Low	Max	25 °C	-	0.07	0.25	V	$D_{1} = 10 k_{0}$
Output Voltage Low	Vol	-40 °C to +85 °C	-	-	0.3	V	R _L = 10 kΩ
Larga Signal Valtaga Cain	٨	25 °C	60	75	-	- dB	-
Large Signal Voltage Gain	Av	-40 °C to +85 °C	55	-	-		
Common-mode Input Voltage Range ^(Note 1)	VICMR	25 °C	0	-	V _{DD} -2.0	V	-
Common-mode Rejection	CMRR	25 °C	50	70	-	dB	
Ratio	CIVIRR	-40 °C to +85 °C	45	-	-	uБ	-
Power Supply Rejection	PSRR	25 °C	50	70	-	dB	
Ratio	PORK	-40 °C to +85 °C	40	-	-	uБ	-
Output Source Current ^(Note 2)	1	25 °C	2	7.5	-	mΛ	Vout = Vdd-0.4 V
	Іон	-40 °C to +85 °C	1	-	-	mA	Absolute value
Output Sink Current ^(Note 2)	1	25 °C	3.5	6.0	-	mΛ	V _{OUT} = V _{SS} +0.4 V
	IOL	-40 °C to +85 °C	1	-	-	mA	Absolute value
Slew Rate	SR	25 °C	-	10	-	V/µs	C∟= 10 pF
Gain Bandwidth Product	GBW	25 °C	-	8	-	MHz	G = 40 dB
Total Harmonic Distortion + Noise	THD+N	25 °C	-	0.05	-	%	$V_{OUT} = 4 V_{P-P},$ LPF = 80 kHz, f = 1 kHz
Channel Separation	CS	25 °C	-	120	-	dB	f = 1 kHz, input referred

(Note 1) Not 100% tested.

(Note 2) Consider the power dissipation of the IC under high temperature environment when selecting the output current value. When the output pin is shortcircuited continuously, the output current may decrease due to the temperature rise by the heat generation of inside the IC.

Electrical Characteristics (Unless otherwise specified V_{DD} = 12 V, V_{SS} = 0 V, Ta = 25 °C) - continued $_{\odot}\text{BD77504FV}$

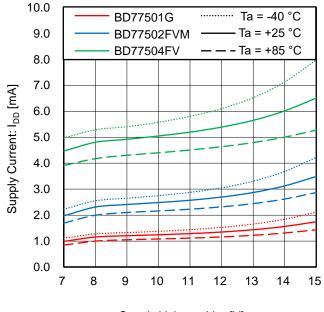
Deremeter	Symbol	Temperature		Limit		Unit	Conditions
Parameter		Range	Min	Тур	Max		
Input Offset Voltage	Vio	25 °C	-	4	27	mV	Absolute value
Input Offset Current	l _{io}	25 °C	-	0.001	-	nA	Absolute value
Input Bias Current	lв	25 °C	-	0.001	-	nA	Absolute value
Supply Current	1	25 °C	-	5.2	12.0	mA	$\mathbf{P} = \mathbf{e} \cdot \mathbf{C} = 0 \mathbf{d} \mathbf{P}$
Supply Current	IDD	-40 °C to +85 °C	-	-	18.0		R _L = ∞, G = 0 dB
Output Voltage High	Vон	25 °C	-	0.06	0.25	V	R∟= 10 kΩ,
Output voltage high	VOH	-40 °C to +85 °C	-	-	0.3	V	V _{OH} = V _{DD} -V _{OUT}
Output Voltage Low	Vol	25 °C	-	0.07	0.25	V	R∟= 10 kΩ
Output voltage Low	VOL	-40 °C to +85 °C	-	-	0.3	V	$M_{\rm L} = 10 \text{ M}_{2}$
Large Signal Voltage Gain	Δ.,	25 °C	60	75	-	– dB	-
	Av	-40 °C to +85 °C	55	-	-		
Common-mode Input Voltage Range ^(Note 1)	VICMR	25 °C	0	-	V _{DD} -2.0	V	-
Common-mode Rejection	CMRR	25 °C	50	70	-	dB	_
Ratio	CIVIER	-40 °C to +85 °C	45	-	-	uБ	-
Power Supply Rejection	PSRR	25 °C	50	70	-	dB	_
Ratio	FORM	-40 °C to +85 °C	40	-	-	uВ	-
Output Source Current ^(Note 2)	Іон	25 °C	2	7.5	-		V _{OUT} = V _{DD} -0.4 V
Output Source Current	IOH	-40 °C to +85 °C	1	-	-	mA	Absolute value
Output Sink Current ^(Note 2)	IOL	25 °C	3.5	6.0	-	mA	V _{OUT} = V _{SS} +0.4 V
	IOL	-40 °C to +85 °C	1	-	-	IIIA	Absolute value
Slew Rate	SR	25 °C	-	10	-	V/µs	C∟= 10 pF
Gain Bandwidth Product	GBW	25 °C	-	8	-	MHz	G = 40 dB
Total Harmonic Distortion + Noise	THD+N	25 °C	-	0.05	-	%	V _{OUT} = 4 V _{P-P} , LPF = 80 kHz, f = 1 kHz
Channel Separation	CS	25 °C	-	120	-	dB	f = 1 kHz, input referred

(Note 1) Not 100% tested.

(Note 2) Consider the power dissipation of the IC under high temperature environment when selecting the output current value. When the output pin is shortcircuited continuously, the output current may decrease due to the temperature rise by the heat generation of inside the IC.

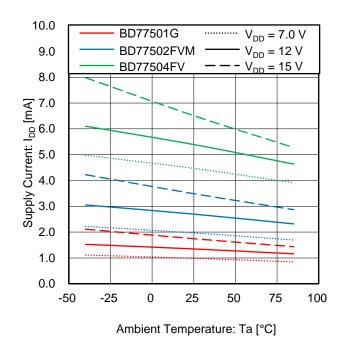
Typical Performance Curves

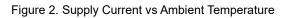
 $V_{SS} = 0 V$

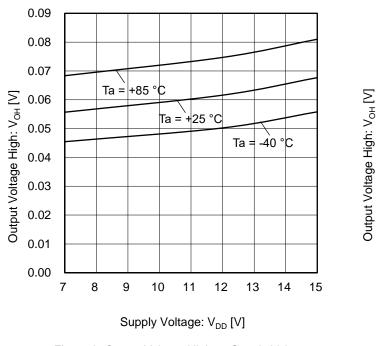


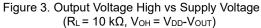
Supply Voltage: V_{DD} [V]

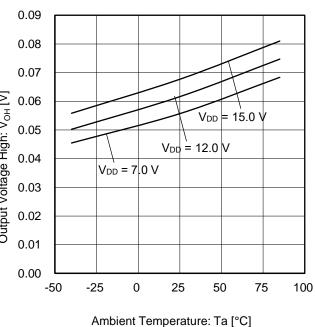
Figure 1. Supply Current vs Supply Voltage









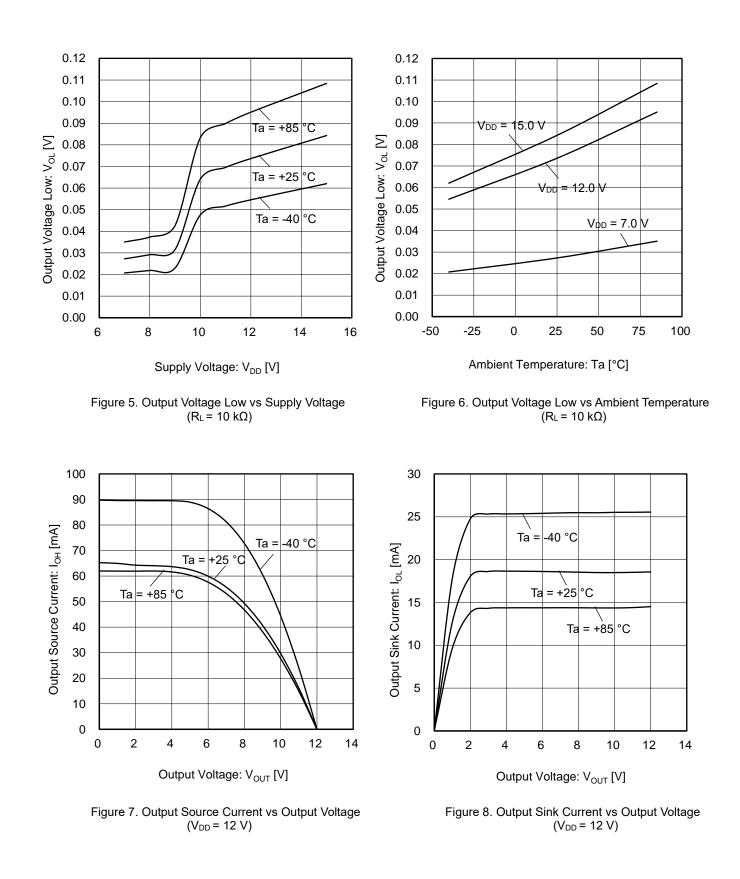




 $(R_L = 10 \ k\Omega, V_{OH} = V_{DD} - V_{OUT})$

Typical Performance Curves - continued

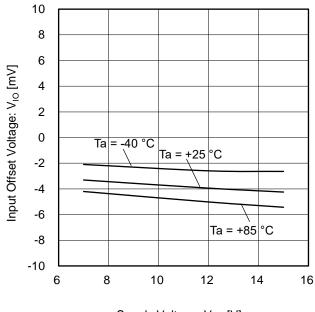
 $V_{SS} = 0 V$



(Note) The above data are measurement value of typical sample; it is not guaranteed.

Typical Performance Curves - continued

 $V_{SS} = 0 V$



Supply Voltage: V_{DD} [V]

Figure 9. Input Offset Voltage vs Supply Voltage

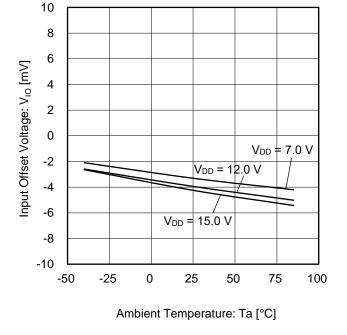
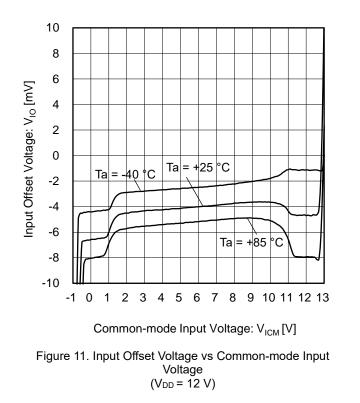
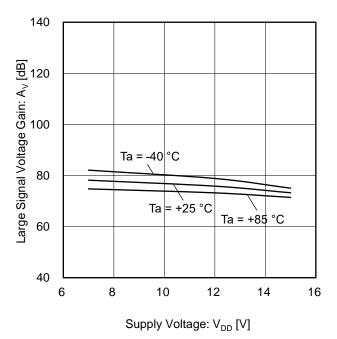
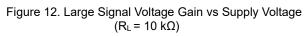


Figure 10. Input Offset Voltage vs Ambient Temperature

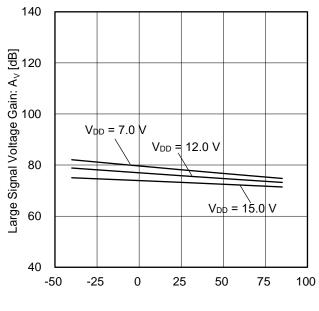






Typical Performance Curves - continued

 $V_{SS} = 0 V$



Ambient Temperature: Ta [°C]

Figure 13. Large Signal Voltage Gain vs Ambient Temperature

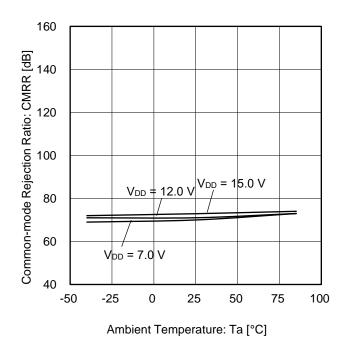


Figure 15. Common-mode Rejection Ratio vs Ambient Temperature

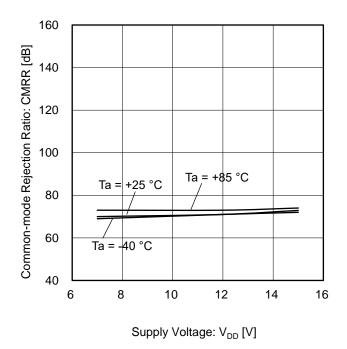


Figure 14. Common-mode Rejection Ratio vs Supply Voltage

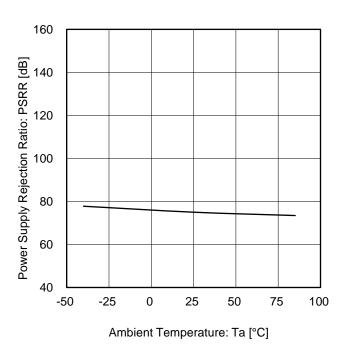
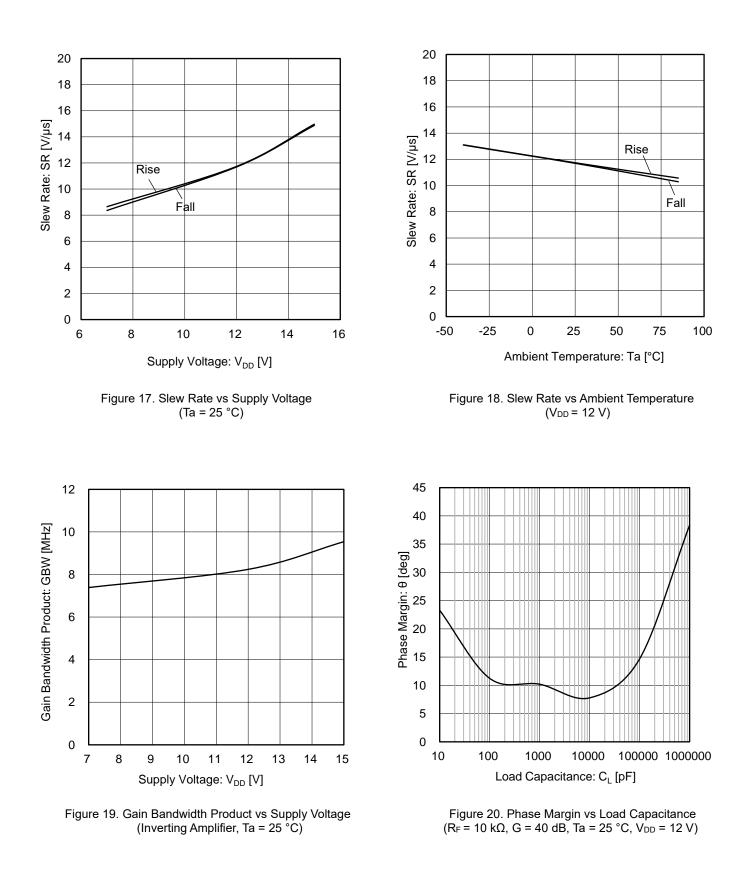


Figure 16. Power Supply Rejection Ratio vs Ambient Temperature

Typical Performance Curves – continued

 $V_{SS} = 0 V$

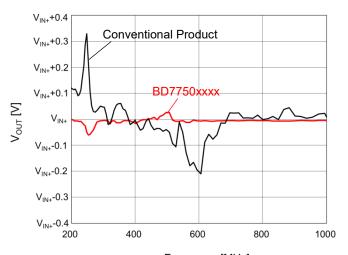


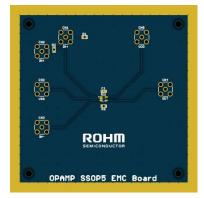
Application Information

ÉMI Immunity

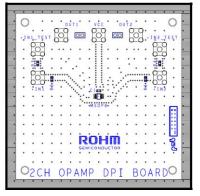
BD7750xxxx series have high tolerance for electromagnetic interference from the outside because they have EMI filter, and the EMI design is simple. They are most suitable to replace from conventional products. The data of the IC simple substance on ROHM board are as follows. The test condition is based on ISO11452-2.

<Test Condition> Based on ISO11452-2 Test Circuit: Voltage Follower V_{DD}: 12 V V_{IN+}: 6 V Test Method: Substituted Law (Progressive Wave) Field Intensity: 200 V/m Test Wave: CW (Continuous Wave) Frequency: 200 MHz to 1000 MHz (2 % step)





EMI Evaluation Board (BD77501G)

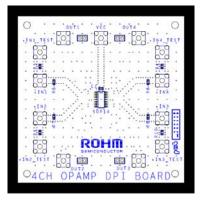


EMI Evaluation Board (BD77502FVM)

Figure 22. EMI Evaluation Board

Frequency [MHz]

Figure 21. EMI Characteristics



EMI Evaluation Board (BD77504FV)

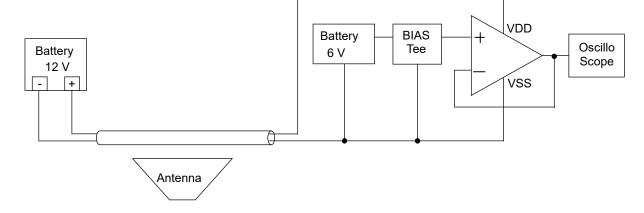


Figure 23. Measurement Circuit of EMI Evaluation

(Note) The above data is obtained using typical IC simple substance on ROHM board. These values are not guaranteed. Design and Evaluate in actual application before use.

Application Information - continued

1. Unused Circuits

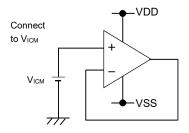
When there are unused circuits, it is recommended that they are connected as in the right figure, and set the non-inverting input pin to electric potential within the input common-mode voltage range (V_{ICM}).

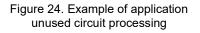
2. Input Voltage

Applying V_{DD} +0.3V to the input pin is possible without causing deterioration of the electrical characteristics or destruction, regardless of the supply voltage. However, this does not ensure circuit operation. Note that the circuit operates normally only when the input voltage is within the common-mode input voltage range of the electric characteristics.

3. Power Supply (single/dual)

The Op-Amp operates when the voltage is supplied between the VDD and VSS pin. Therefore, the single supply Op-Amp can be used as dual supply Op-Amp as well.





4. Output Capacitor

When the VDD pin is shorted to VSS (GND) electric potential in a state where electric charge is accumulated in the external capacitor that is connected to the output pin, the accumulated electric charge flow through parasitic elements or pin protection elements inside the circuit and discharges to the VDD pin. It may cause damage to the elements inside the circuit (thermal destruction). When using this IC as an application circuit which does not constitute a negative feedback circuit and does not occur the oscillation by an output capacitive load such as a voltage comparator, connect a capacitor of 0.1 μ F or less to the output pin to prevent IC damage caused by the accumulation of electric charge as mentioned above.

5. Oscillation by Output Capacitor

Pay attention to the oscillation by capacitive load in designing an application which constitutes a negative feedback loop circuit with this IC.

6. Handling the IC

Applying mechanical stress to the IC by deflecting or bending the board may cause fluctuations of the electrical characteristics due to the piezo resistance effects. Pay attention to defecting or bending the board.

Application Examples

Voltage Follower

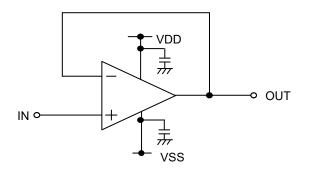


Figure 25. Voltage Follower Circuit

Using this circuit, the output voltage (V_{OUT}) is configured to be equal to the input voltage (V_{IN}). This circuit also stabilizes the output voltage (V_{OUT}) due to high input impedance and low output impedance. Computation for output voltage (V_{OUT}) is shown below.

$$V_{OUT} = V_{IN}$$

oInverting Amplifier

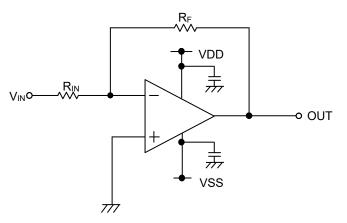


Figure 26. Inverting Amplifier Circuit

For inverting amplifier, input voltage (V_{IN}) is amplified by a voltage gain which depends on the ratio of R_{IN} and R_F, and then it outputs phase-inverted voltage. The output voltage is shown in the next expression.

$$V_{OUT} = -\frac{R_F}{R_{IN}} V_{IN}$$

This circuit has input impedance equal to RIN.

oNon-inverting Amplifier

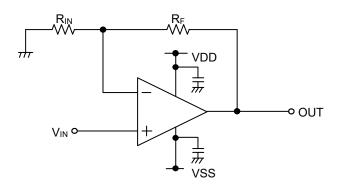


Figure 27. Non-inverting Amplifier Circuit

For non-inverting amplifier, input voltage (V_{IN}) is amplified by a voltage gain, which depends on the ratio of R_{IN} and R_F . The output voltage (V_{OUT}) is in-phase with the input voltage (V_{IN}) and is shown in the next expression.

$$V_{OUT} = \left(1 + \frac{R_F}{R_{IN}}\right) V_{IN}$$

Effectively, this circuit has high input impedance since its input side is the same as that of the operational amplifier.

I/O Equivalence Circuits oBD77501G

Ъυ	D//501G					
	Pin No.	Pin Name	Pin Description	Equivalence Circuit		
	4	OUT	Output			
	1 3	+IN -IN	Input			

oBD77502FVM

·						
	Pin No.	Pin Name	Pin Description	Equivalence Circuit		
	1 7	OUT1 OUT2	Output			
	2 3 5 6	-IN1 +IN1 +IN2 -IN2	Input			

I/O Equivalence Circuits - continued oBD77504FV

Pin No.	Pin Name	Pin Description	Equivalence Circuit
1 7 8 14	OUT1 OUT2 OUT3 OUT4	Output	
2 3 5 6 9 10 12 13	-IN1 +IN1 +IN2 -IN2 -IN3 +IN3 +IN4 -IN4	Input	4 9, 10, 12, 13 (1) (4) (4) (4) (4) (4) (4) (4) (4) (4) (4

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes – continued

10. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example, (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

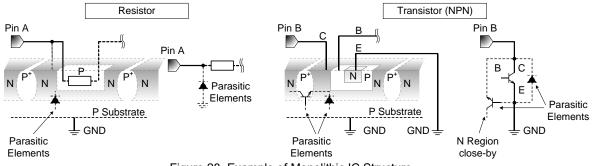
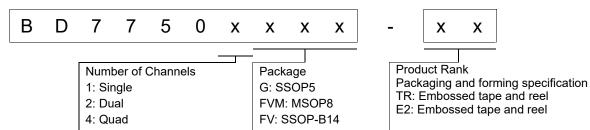


Figure 28. Example of Monolithic IC Structure

11. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

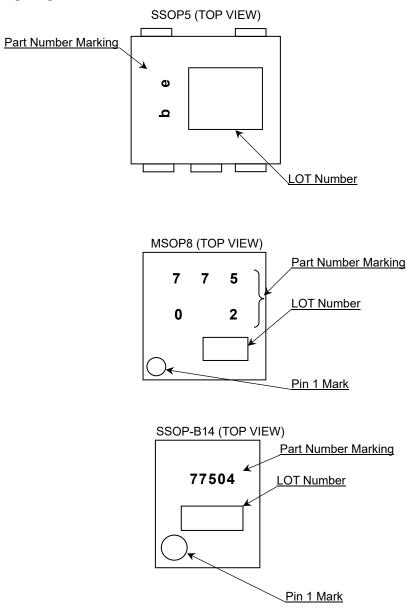
Ordering Information



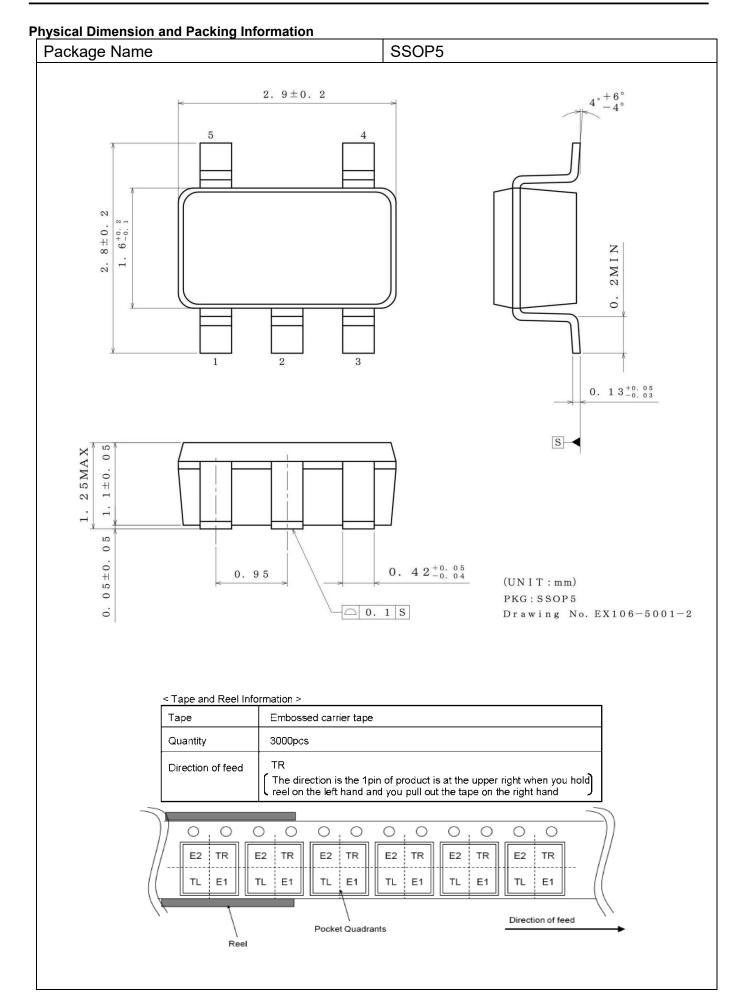
Lineup

Operating Temperature Range	Operating Supply Voltage	Number of Channels	Pac	kage	Orderable Part Number
	7.0 V to 15.0 V ±3.5 V to ±7.5 V	Single	SSOP5	Reel of 3000	BD77501G-TR
-40 °C to +85 °C		Dual	MSOP8	Reel of 3000	BD77502FVM-TR
		Quad	SSOP-B14	Reel of 2500	BD77504FV-E2

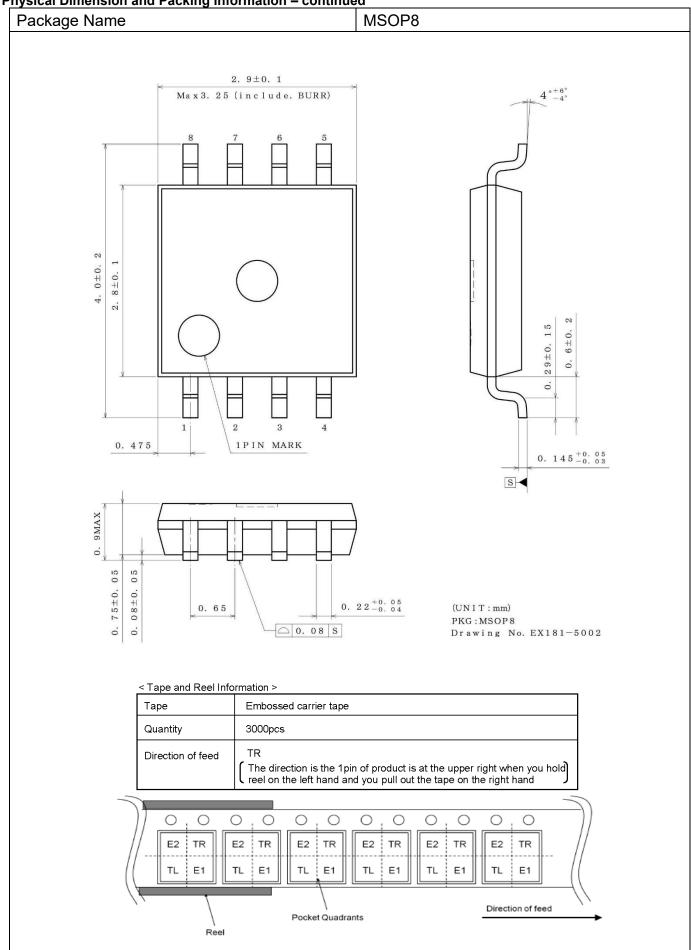
Marking Diagram



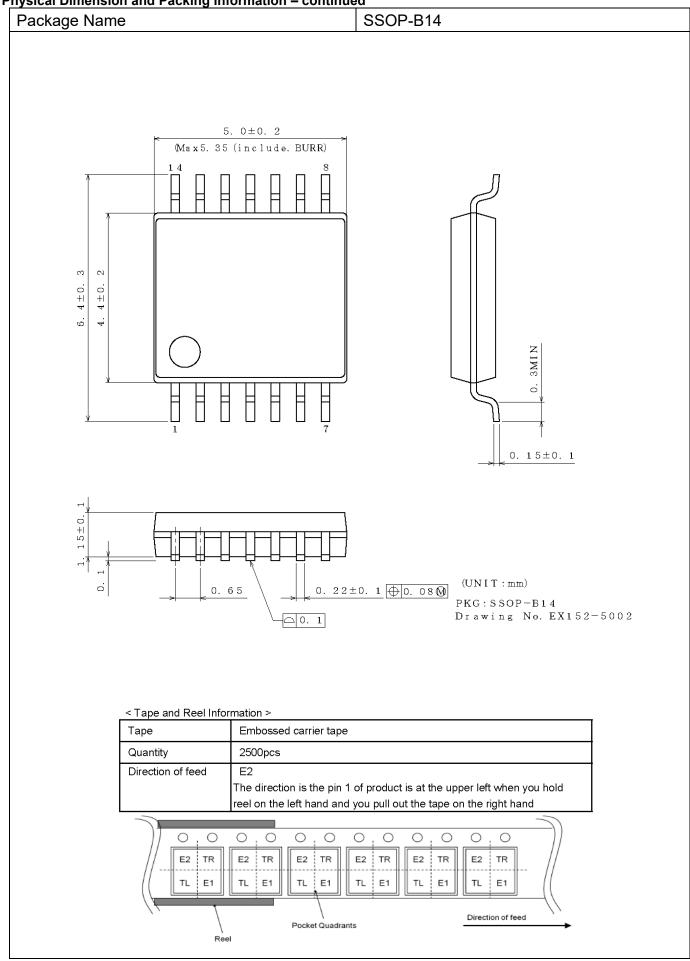
Datasheet



Physical Dimension and Packing Information – continued







Revision History

Date	Revision	Changes
11.Nov.2019	001	New Release
06.Jul.2020	002	Add Lineup
30.Oct.2020	003	Add Lineup

Notice

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JÁPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSⅢ
CLASSⅣ	CLASSII	CLASSⅢ	CLASSI

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 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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